

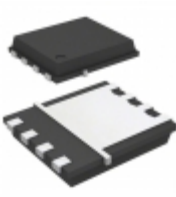
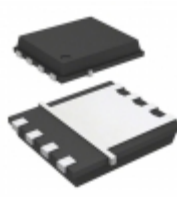



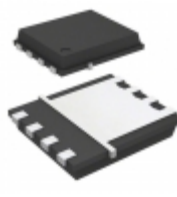
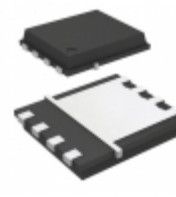
	<h2>BSC011N03LS</h2>
	<p>Hersteller-Teilenummer: BSC011N03LS</p> <p>Hersteller / Marke: International Rectifier (Infineon Technologies)</p> <p>Teil der Beschreibung: BSC011N03LS Infineon Technologies</p> <p>Datenblätter:  BSC011N03LS.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1489 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	BSC011N03LS
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	BSC011N03LS Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1489 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	PG-TDSON-8
Verlustleistung (max)	2.5W (Ta), 96W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	37A (Ta), 100A (Tc)
Rds On (Max) @ Id, Vgs	1.1 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	72nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4700pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

BSC011N03LS ist neu im Original, Suche BSC011N03LS Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie BSC011N03LS International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage BSC011N03LS: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>BSC011N03LSATMA1 INFINEO INFINEO PG-TSDS</p>	 <p>BSC011N03LSI International Rectifier (Infineon Technologies) BSC011N03LSI Infineon Technologies</p>	 <p>BSC010NE2LSIATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 25V 38A TDSON-8</p>	 <p>BSC010NE2SXT INFINEON INFINEON TDSON-8-4</p>
 <p>BSC010NE2LSG infineon/ BSC010NE2LSG infineon/</p>	 <p>BSC011N03LSIATMA1 INFINEO INFINEO PG-TSDS</p>	 <p>BSC011N03LSATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 30V 100A 8TDSON</p>	 <p>BSC010NE2LSI International Rectifier (Infineon Technologies) BSC010NE2LSI Infineon Technologies</p>

heiße Teile

Mehr

BSC009NE2LS	BSC009NE2S	BSC010NE2LS	BSC010NE2LSI	BSC011N03NS3G
BSC014N03LS	BSC014N03LSG	BSC014N03MSG	BSC014N03NS3G	BSC014NE2LSI
BSC014NE2LSIXT	BSC014NE2S	BSC016N03LS	BSC016N03LSG	BSC016N03MSG
BSC016N04LSG	BSC017N04NS3G	BSC017N04NSG	BSC018N04LSG	BSC018NE2LS
BSC018NE2LSI	BSC018NE2SXT	BSC019N02KS	BSC019N02KSG	BSC019N02NS3G
BSC019N04NS3G	BSC019N04NSGATMA1	BSC020N025S	BSC020N025SG	BSC020N03LSG
BSC020N03MSG	BSC020N03NS3G	BSC022N03S	BSC022N03SG	BSC022N04LS
BSC022N04NS3G	BSC024N025SG	BSC024NE2LS	BSC024NE2SXT	BSC025N03LSG
BSC025N03MS	BSC025N03MSG	BSC025N03NS3G	BSC026N02NS3G	BSC026N04LS
BSC026N08NS5	BSC026NE2LS5	BSC027N03SG	BSC027N04LSG	BSC027N04NS3G

Contact us: Info@Y-IC.com

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